



# A WIDE STOP BAND 6-POLE STEPPED IMPEDANCE LOW PASS FILTER USING DOUBLE EQUILATERAL U- SHAPED DEFECTED GROUND STRUCTURE

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**ABSTRACT:** Filters play an important role in microwave applications. Micro strip filters play various role in wireless communication or mobile communication systems. There is an increasing demand for newer microwave and millimeter wave system to meet the emerging telecommunication challenge with respect to size, cost and performance. This paper presents a compact microstrip stepped impedance lowpass filter with ultra-wide stop band. A compact double equilateral U-shaped defected ground structure (DGS) unit is proposed. In contrast to a single finite attenuation pole characteristic offered by the conventional dumbbell DGS the proposed DGS unit provide dual finite attenuation poles that can be independently controlled by the DGS lengths. A 1.5-GHz microstrip low pass filter using five cascaded double U-shaped DGS unit is designed and compared with conventional DGS low pass filter.

**Keywords:** low pass filter, Dielectric constant, Microstrip filter, Defected ground structure (DGS).

## I. INTRODUCTION

With the rapid development of microwave communication systems, microwave low pass filters (LPFs) with low cost, small size, low insertion loss, high selectivity, and wide stop band have attracted wide attention for years. Various technologies have been developed in practice, but the microstrip LPFs are more dominant due to the reduction of circuit sizes. Stepped-impedance structure is a relatively popular way to implement microstrip LPFs by cascading very high and very low characteristic impedance transmission line alternatively. Applications of defected ground structure (DGS) in radio frequency/microwave (RF/MW) circuits find numerous advantages like circuitry size reduction and superior response suppression. The conventional DGS element uses a dumbbell-shaped pattern etched in the ground plane. This DGS element exhibits a bandgap characteristic at some frequency, which is mainly attributed by a finite attenuation pole. The relationship between attenuation pole frequency and the physical dimensions of the DGS unit was also explored. Recently its usage in the low pass filter for wide stop band implementation has been focused and demonstrated. In fact, these DGS elements with uniform dimensions are cascaded in a one dimension (1-D) periodic pattern in order to realize wider stop band even the pass band ripple is concerned. To counteract this ripple problem, nonuniform configuration has been proposed to achieve much wider stopband and smaller passband ripples simultaneously. It is found that the more DGS elements are used, the wider stopband is achieved.

In this paper low pass filter is optimized for high performance and efficient. Microstrip technology is used for simplicity and easy of fabrication. The design and simulation are performed using 3D full wave Electromagnetic simulator IE3D.

## II. U-SHAPED DGS UNIT

Despite the different periodic DGS proposed in the past, the main laggard of these approaches is the excess circuitry size introduction due to the cascade DGS configuration. In order to realize simultaneously wide stopband and size minimization for the microstrip low pass filter with DGS a double equilateral U-shaped DGS unit that can offer dual attenuation poles is proposed. The paper control of these two attenuation poles can significantly suppress the spurious response in the stopband with much smaller defected ground area. A microstrip low pass filter prototype with a cut off

frequency of 1.5GHz and wide stop band up to 10GHz has been designed and experimentally characterized to demonstrated the proposed DGS usefulness.

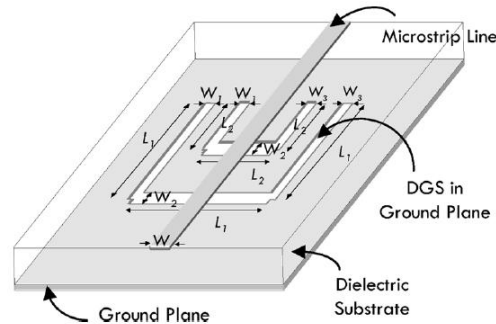


Fig. 1 Three dimensional view of proposed DGS unit

The proposed double equilateral U shaped DGS unit shown in fig.1, it has a 6-pole ordinary microstrip low pass filter on the top and five equilateral U shaped pattern that are symmetrically etched in the ground plane. Each U shaped pattern consist of three etched lines with the same length but the different width ( $W_1, W_2,$  and  $W_3$ ) by setting these five U shaped pattern with different length ( $L_1, L_2$  where  $L_1 > L_2$ ). The smaller one can easily be embedded inside the larger ones with the open end alignment.

### III. FILTER DESIGN METHOD

The design of low pass filters involves two main steps. The first one is to select an appropriate low pass prototype. The choice of the type of response, including pass band ripple and the no of reactive element will depend on the required specification. The element values of low pass prototype filter, which are usually normalized to make a source impedance  $g_0=1$  and a cut off frequency  $\Omega_c = 1.0$ , are than transform to L-C element for the desired cut off frequency and the desired source impedance, which is normally 50 ohms for microstrip filters. The next main step in the design of microstrip low pass filter is to find and appropriate microstrip realization that approximately lumped element filter. The element value low pass prototype with maximally flat response at pass band ripple factor  $L_{AR}=0.1\text{dB}$ . Characteristic impedance source/load  $Z_0=50\text{ohms}$ , are taken from normalized value  $g_i$  i.e.  $g_1, g_2, g_3, g_4, \dots, g_n$ . The filter is assumed to be fabricated on a substrate a dielectric constant  $\epsilon_r$  and of thickness  $h$  mm for angular (normalized) cut off frequency  $\Omega_c$ , using the element transformation.

#### A. Filter specifications:

Relative Dilectric constant,  $\epsilon_r = 4.4$   
Height of substrate,  $h=1.6$  mm  
The substrate used-  
The loss tangent  $\tan\delta=0.02$   
Input impedance  $Z_0 = 50\Omega$   
 $\Omega_c = 1\Omega$   
Cutoff frequenecy  $f_c=2.4\text{GHz}$

#### B. Designe Equation

Determine the valus of the prototype elements to realize the specifications. Aiso we have taken the

$$L_i = (Z_0 / g_0) (\Omega_c / 2\pi f_c) g_i$$

$$C_i = (g_0 / Z_0) (\Omega_c / 2\pi f_c) g_i$$

$$I_L = \lambda_{g1} / 2\pi \sin^{-1}(\omega_c L_i / Z_{oL})$$

$$I_c = \lambda_{gc} / 2\pi \sin^{-1}(\omega_c C_i Z_{oc})$$

To calculate the width of capacitor and inductor we use the following formula

$$W/h = 8 \exp(A) / \exp(2A) - 2$$

$$Z_c = \eta / 2\pi \sqrt{\epsilon_r \epsilon} \left[ \ln \left( \frac{8h}{w} + \frac{0.25w}{h} \right) \right]$$

The effective dielectric constant can be found by the following formula

$$\epsilon_{re} = (\epsilon_r + 1) / 2 + (\epsilon_r - 1) / 2 [(1 + 12h/w) - 0.5]$$

#### IV. DIMENTION OF THE FILTER

Table I: Dimensions of the Stepped Impudence Low pass filter (For N=6)

Sr.no	$Z_i = Z_h$ or $Z_l$ ( $\Omega$ )	$W_i$ (mm)	$L_i$ (mm)
1	93	0.83855	10.348
2	23	9.2593	9.72
3	93	0.83855	23.94
4	23	9.2593	7.731
5	93	0.83855	23.942
6	23	9.2593	9.32
7	50	3.679	3

#### V. SIMULATED RESULTS

The proposed filter is composed of sixth-order stepped impedance LPF of varied width and U-shaped DGS unit. The feed line is designed 50 ohm all geometric dimensions are shown in table-1 and fig. 2, 3, 4 shows simulated results of the proposed microstrip low pass filter. For the simulation purpose we have used method of moment based full-wave EM solver IE3D.

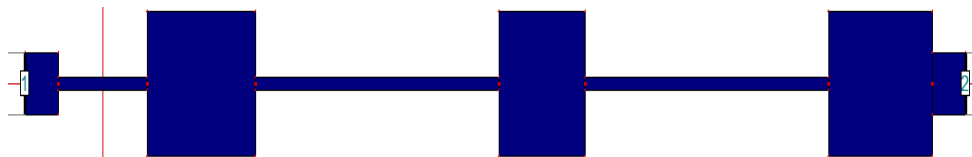


Fig. 2: Layout of the simulated 6-pole Stepped Impedance Microstrip LPF (Top Layer)

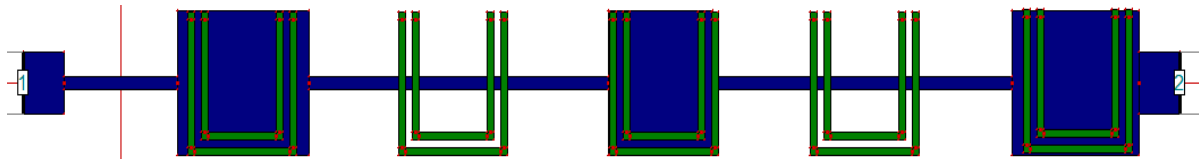


Fig. 3: Layout of the U-shaped cascaded DGS. (bottom Layer)

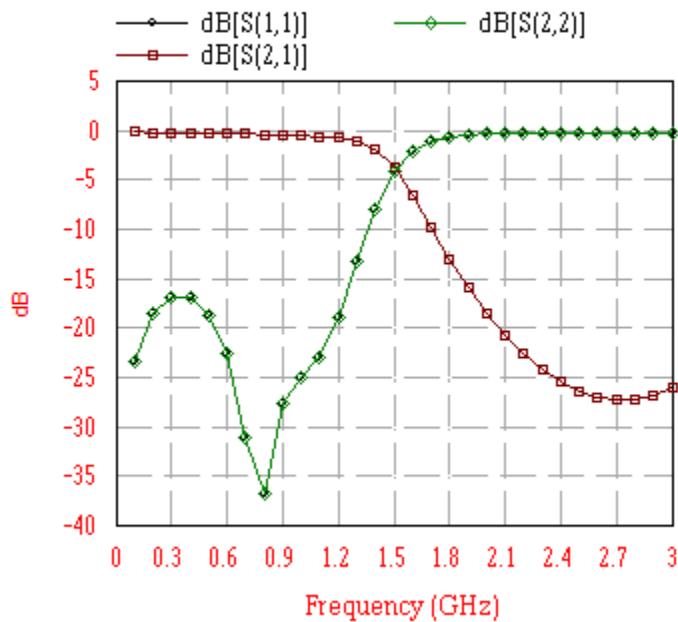


Fig. 4: Simulated result of stepped impedance LPF using U-shaped DGS. This graph is plotted between S(1,1) and S(1,2)

## VI. CONCLUSION

The paper present an efficient approach to improve conventional stepped impedance lowpass filter transition band performance with a miniaturized area. from the simulated results the lowpass filter based on the proposed DGS unit offers significant improvement of the stopped band attenuation and size reduction when compared with the conventional low pass filter. Thus this method is very flexible for configuration and specially use full low pass filter design to develop sharp transition band.

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## REFERENCES

- [1] D.M. Pozar "Microwave Engineering", John Wiley, 2000.
- [2] "IE3D user's Manual," Zeland Software, Inc. , Jan. 2001, Release 8
- [3] S. Pirani, J. Nourinia, and C. Ghobadi, "Small ultra wide band pass filter with notched band," IEEE Microw. Wireless Compon. Lett., Vol. 20, no. 8, pp. 444-446, Aug.2010
- [4] R. Ghatak, P. Sarkar, R. K. Mirshra, D. R. Poddar, "a compact ultra wide band pass filter with embadedm SIR as band notch structure," IEEE Microw., wireless compon.,lett., vol. 21, no. 5, pp261-263, may 2011.
- [5] S.Sun and L. Zhu, "multimode resonator based band pass filter ,," IEEE Microw., Mag., vol.10, no.2, pp.88-98, april 2009.
- [6] B. Yao, Y. Zhu, Q.Cao, and Y.Chen, "compact Ultra wide band pass filter with improved upper stop band performance," IEEE microw., wireless compon., lett. , vol. 19, no.1,pp.27-29, jan 2009.
- [7] J.Garcia-Garcia, J. Bonache,and F. martin, "application of electromagnetic band gap to design of ultra wide band pass filters with good out of the band performance," IEEE trans micro. Theoty Tech., vol 54,no.12, pp.4136-4140, dec.2006.

## BIOGRAPHY



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